Oral presentation | 15 Crystal Engineering | 15.6 Group IV Compound Semiconductors (SiC)

[15p-C302-1~18] 15.6 Group IV Compound Semiconductors (SiC)

Hidekazu Tsuchida (CRIEPI), Satoshi Tanimoto (Nissan ARC)
Thu. Sep 15, 2016 1:45 PM - 7:00 PM  C302 (Nikko Houou)

△: Presentation by Applicant for JSAP Young Scientists Presentation Award
▲: English Presentation
▼: Both of Above
No Mark: None of Above

1:45 PM - 2:15 PM

[15p-C302-1][JSAP Best Review Paper Award Speech] Material science and device physics in SiC technology for high-voltage power devices

〇Tsunenobu Kimoto¹ (1.Kyoto Univ.)
Keywords: JSAP Best Review Paper Award Speech